

A New Approach for Transistor-Clamped H-Bridge Multilevel Inverter with voltage Boosting Capacity

Suparna Buchke, Prof. Kaushal Pratap Sengar

TIT, Madhya Pradesh, India

ABSTRACT

Multilevel converters offer high power capability, resulting with lower output harmonics and lower commutation losses. Their main disadvantage is their complexity, requiring a great number of power devices and passive components, and a rather complex control circuitry. This paper presents a new topology of the multilevel inverter with feature like output voltage boosting capability along with capacitor voltage balancing. The proposed multilevel inverter uses conventional transistor clamped H-bridge (TCHB) with an bidirectional switch and four auxiliary switches producing a boost output voltage. The single unit of new topology produces five-level output with output voltage double the input DC voltage where as a single unit of conventional H-bridge produces three-level output voltage similar to input DC voltage. A novel universal control scheme is used which results in balanced distribution of power among H-bridge cells. This control scheme can also be used for the charge balance control with multiple input DC sources in any given topology. The analysis of the output voltage harmonics is carried out and compared with previous topology and the conventional cascaded H-bridge inverter topology. The proposed multilevel inverter topology is modelled using matlab/simulink. From the results the proposed inverter provides more output voltage.

Keywords : Multilevel Inverter, Cascaded H-Bridge, Multicarrier Phase Width Modulation, Transistor Clamped Inverter, Cascaded Neutral –Point Clamped Inverter.

I. INTRODUCTION

There are various application varying from medium voltage to high voltage high power application which requires DC to AC conversion using multilevel inverters. The research on multilevel inverter is ongoing further to reduce the number of switching devices count to reduce the manufacturing cost, capacitor voltage balancing. The inverters with number of voltage levels equal to three or above than that are known as the multilevel inverters. Multilevel inverters are capable of producing high power high voltage as the unique structure of the multilevel voltage source inverter allows to reach high voltages with low harmonics without the use of transformers or series connected synchronized switching devices. As the number of voltage levels increases, the harmonic content of the output voltage waveform decreases. The

synthesized multilevel outputs are superior in quality which results in reduced filter requirements [1].

There are three major multilevel voltage source inverter topologies neutral-point clamped inverter (i.e diode clamped), flying capacitor (capacitor-clamped) and cascaded H-bridge multilevel inverter. There are also various other topologies which have been proposed and have successfully adopted in various industrial applications. The novel universal multicarrier PWM control scheme is used. This paper mainly focuses mainly on the cascaded H-bridge inverter topology. the cascaded multilevel inverter has the potential to be the most reliable out of three topologies. It has the best fault tolerance owing to its modularity a feature that enables the inverter to continue operate at lower power levels after cells failure[2]. Due to the modularity of the cascaded multilevel inverter it can be stacked easily for high power and high voltage applications. The cascaded

multilevel inverter mainly consists of several identical H-bridge cells, which are cascaded, in series from the output side. The cascaded H-bridge (CHB) may further be classified as symmetrical if the DC bus voltage is equal in all the series power cells and as asymmetrical if the DC bus voltage is not same for each power cell. The symmetrical CHB is more advantageous over the asymmetrical CHB in terms of modularity, maintenance and cost. In case of the asymmetrical CHB DC bus voltage is varied in each power as per the requirement to increase the voltage levels [2]. In case of the symmetrical CHB the voltage, level can be increased without varying the DC voltage with same number of power cells. The transistor clamped topology is popular now a days a provides provision to increase the output levels by taking different voltage levels from the series stacked capacitors [1]. In this paper the new configuration of the symmetrical H-bridge is proposed which produces a five-level output voltage similar to conventional transistor clamped topology. Instead of three-level as in case of conventional H-bridge. However, this new proposed topology produces the boost output voltage in comparison to conventional transistor clamped topology, which also produces the five-level output but the output voltage equal to the DC voltage.

II. METHODS AND MATERIAL

Proposed Inverter Configuration

The conventional cascaded H-bridge inverter consists of DC voltage for each H-bridge and only four switching devices. The value of the DC voltage in each bridge depends whether the configuration is symmetric or unsymmetric. Fig.1 shows the conventional H-bridge. The general block diagram for the proposed inverter is shown in fig.2 and the general configuration of the proposed inverter topology is shown in fig.3 which represents a single cell which produces the five-level output with boost output voltage. It consist of total of 8 switches in a single cell along with an additional bidirectional switch consisting of S11 and S11' which is connected between the first leg of the H-bridge and the capacitor midpoint, enabling five output voltage levels (+2V_{dc}, +V_{dc}, 0, -V_{dc}, -2V_{dc}) based on the switching combination. The switches S21,S31,S41,S51 forms the H-bridge and the switches Sa1,Sa2,Sa3,Sa4 are connected in the same leg which

plays a role in boosting the voltage and the input DC voltage is connected with positive terminal between the switches Sa1 and Sa2 and the negative terminal between the switches Sa3 and Sa4. The capacitor voltage divider is formed by C1 and C2.

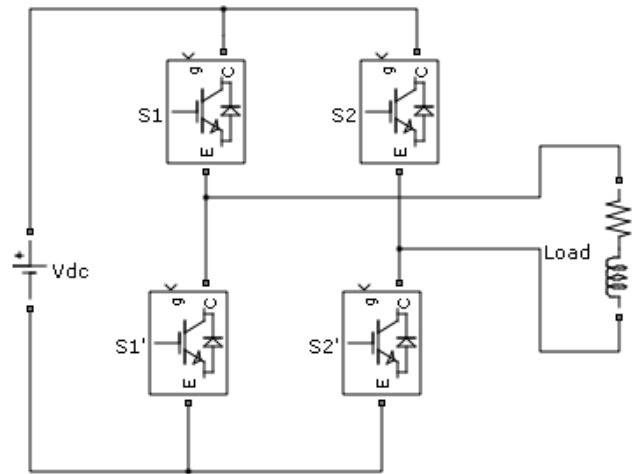


Figure 1. Conventional cascaded H-bridge

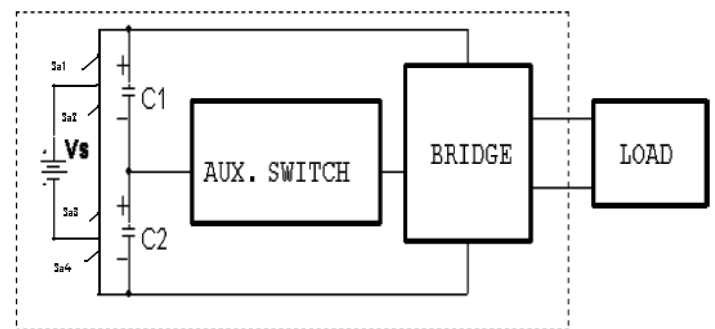


Figure 2. General block diagram of new topology

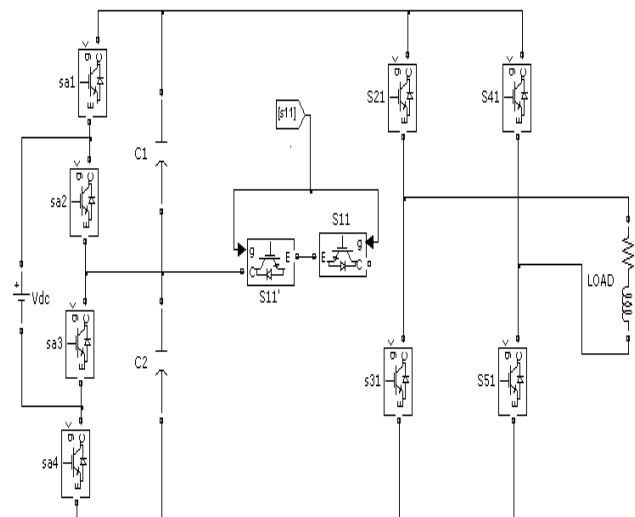


Figure 3. Topology of five-level transistor clamped H-bridge with boost output voltage for each cell

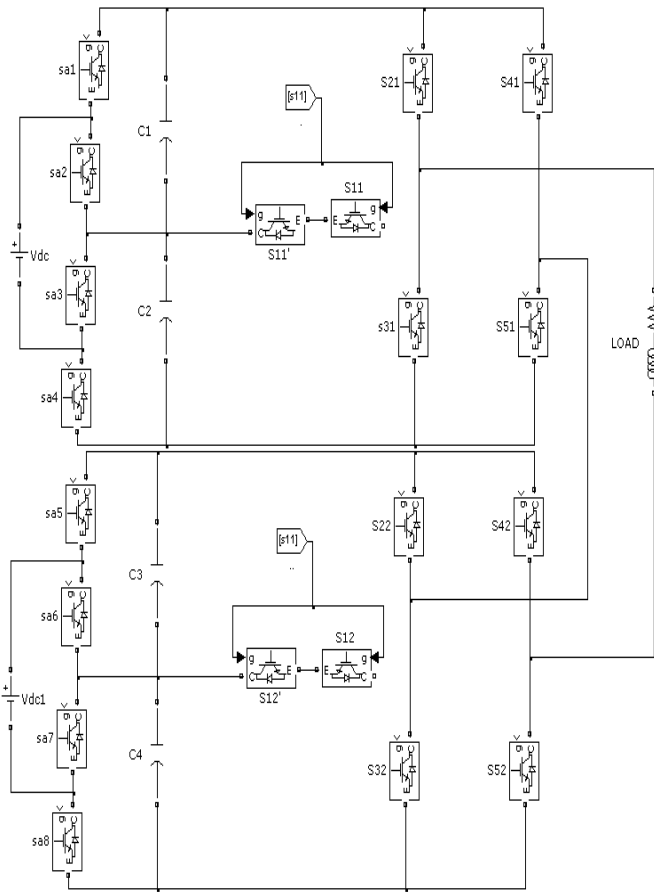


Figure 4. Configuration of the proposed 1-phase transistor clamped cascaded H-bridge inverter using two cells

Operation of proposed inverter topology

The working of the single cell of the proposed inverter topology is explained telling how the required five level output is produced:

1. Maximum positive output that can be produced is the double of the input DC voltage i.e $2V_{dc}$ which is produced when S21 is on connecting the load positive terminal to the load and S51 is on connecting the load negative terminal to the V_{dc} thus the total output voltage is $2V_{dc}$. The output voltage level V_{dc} is obtained when Sa1, S11, S51 and Sa2 gets turned on other switches remaining off.
2. Maximum negative output is $-2V_{dc}$, which is produced when switches S41 and S31 gets turned on connecting the negative and positive terminal of the load respectively to the input source. The negative level $-V_{dc}$ is obtained when switches Sa1, Sa3, S11, S41 are turned on other switches remaining off.

The look up table for the proposed inverter is given in the figure given below.

Voltage level	$+2V_{dc}$	$+V_{dc}$	0	$-V_{dc}$	$-2V_{dc}$
Sa1	0	0	0	1	0
Sa2	0	1	0	0	0
Sa3	0	0	0	1	0
Sa4	0	1	0	0	0
S11	0	1	0	1	0
S21	1	0	1	0	0
S31	0	0	0	0	1
S41	0	0	1	1	1
S51	1	1	0	0	0

Table 1. Look up table for the proposed TCHB

Voltage level	+4 V	+3 V	+2 V	+1 V	0 V	-1V	-2V	-3V	-4V
Sa1	0	0	0	0	0	1	1	0	0
Sa2	0	0	1	1	0	0	0	0	0
Sa3	0	0	0	0	0	1	1	0	0
Sa4	0	0	1	1	0	0	0	0	0
S11	0	0	1	1	0	1	1	0	0
S21	1	1	0	0	1	0	0	0	0
S31	0	0	0	0	0	0	0	1	1
S41	0	0	0	0	1	1	1	1	1
S51	1	1	1	1	0	0	0	0	0
Sb1	0	0	0	0	0	0	1	1	0
Sb2	0	1	1	0	0	0	0	0	0
Sb3	0	0	0	0	0	0	1	1	0
Sb4	0	1	1	0	0	0	0	0	0
S12	0	1	0	0	0	0	1	1	0
S22	1	0	1	1	1	1	0	0	0
S32	0	0	0	0	0	0	0	0	1
S42	0	0	0	1	1	1	1	1	1
S52	1	1	1	0	0	0	0	0	0

Table 2. Lookup table for single phase proposed transistor clamped H-bridge inverter

PWM Control Scheme

Multilevel inverter has to synthesize a staircase waveform by using the modulation technique to have the controlled output voltage. There is variety of modulation techniques available. The control technique can be classified as the pulse width modulation, which is considered as the most efficient

method. This PWM is further divided into various PWM techniques such as single pulse PWM, space vector PWM, multiple pulse PWM, phase displacement control [1]. For this proposed topology, we are using the multicarrier based control technique, which can be applied, to all the topologies of the multilevel inverter. For any given number of levels in the output voltage the number of carrier to be used is given as N-1.

Where N is the number of levels in the output voltage. Simply a reference signal is taken which is a sinusoidal signal of 50Hz frequency and this reference is compared with the carrier signal which are the triangular wave. The modulation index we are using in this modulation technique is 0.95. The advantage of this scheme is that it offers the charge balance control in the input DC sources and voltage across the capacitor are also balanced [4].

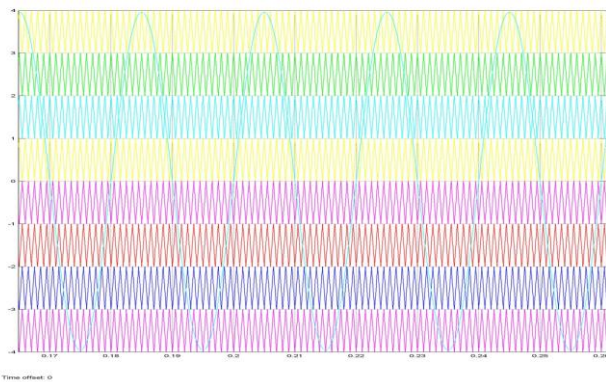


Table 3. Multicarrier based control scheme for the proposed topology

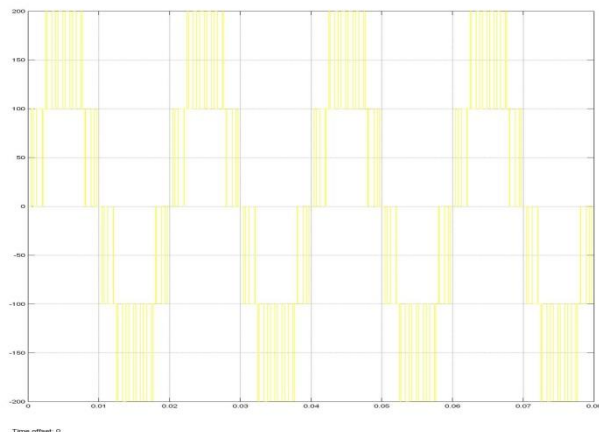


Figure 4. 5-level output voltage waveform of single phase cascaded H-bridge inverter with two cells

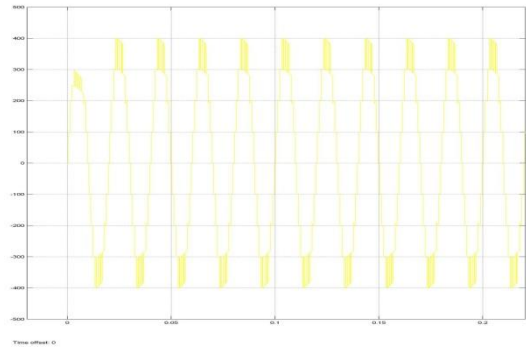


Figure 5. 9-level output voltage waveform of single phase proposed transistor clamped H-bridge inverter with two bridges.

III. RESULTS AND DISCUSSION

Comparison of Proposed Topology with Cascaded H-Bridge Topology

The purpose of research for the multilevel inverter includes to get a quality power output with the reduced number of switching devices, balancing of the capacitors, reduced number of clamping diodes in order to reduce the overall cost of the multilevel inverter. In the proposed multilevel inverter topology, the number of switches is more in comparison to the conventional CHB but we get the five-level in the output voltage, which results in reduced THD. In addition, the input DC voltage source required is half of the voltage source required in the conventional CHB. much superior than the cascaded H-bridge topology in terms of the number of level in the output voltage, magnitude of the output voltage, total harmonic distortion. To produce the same output voltage the cascaded H-bridge has to use the two cells whereas only one cell is required with the proposed topology. Fig.3 is showing the single-phase inverter consisting of two cells of the proposed topology each cell is having input 100V DC voltage and the output ac voltage is 400V each of which is producing 200V. The total harmonic distortion produced by the proposed inverter is 11.49% only, which is very low as compared to the conventional cascaded H-bridge inverter having THD of 37.64%, which is 26.15% more than the proposed topology. In order to produce the nine levels in the output voltage the cascaded H-bridge requires three cells whereas the proposed topology requires only two cells.

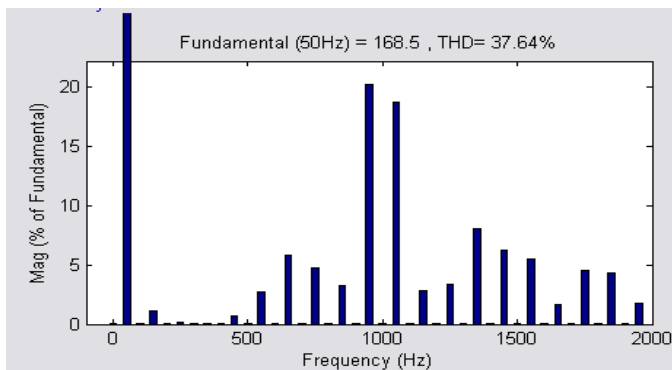


Figure 6. THD in % for single phase cascaded H-bridge multilevel inverter

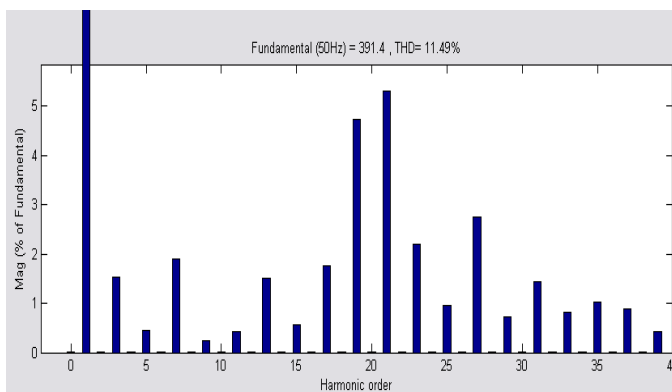


Figure 7. THD in % for double phase cascaded H-bridge multilevel inverter

IV.CONCLUSION

The proposed multilevel inverter topology is much superior to the conventional cascaded H-bridge topology in terms of the number of level in the output voltage, magnitude of the output voltage, total harmonic distortion (THD). To produce the same output voltage the cascaded H-bridge has to use the two cells whereas only one cell is required with the proposed topology or in other words input DC voltage source required in proposed topologi is half of that required in conventional CHB.

V. REFERENCES

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